

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)TYP}$ | I_D |
|---------------|-----------------|-------|
| 40V | 1.8mΩ@10V | 180A |
| | 2.8mΩ@4.5V | |

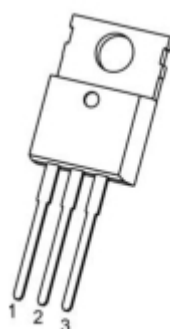
Feature

- Low Gate Charge and Rdson
- Low Reverse transfer capacitances
- 100% Single Pulse avalanche energy Test

Application

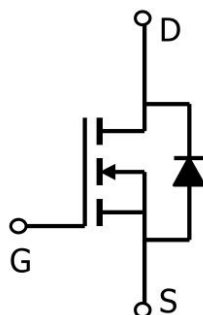
- Power switching application
- DC/DC Converter

Package



TO-220-3L-C(1:G 2:D 3:S)

Circuit diagram



Marking



40N02A =Device Code
****** =Week Code

Absolute maximum ratings

(T_a=25°C unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|------------------|------------|------|
| Drain-Source Voltage | V _{DS} | 40 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Continuous Drain Current(Tc=25°C) | I _D | 180 | A |
| Pulsed Drain Current ² | I _{DM} | 720 | A |
| Single Pulse Avalanche Energy ³ | E _{AS} | 529 | mJ |
| Total Power Dissipation ² (Tc=25°C) | P _D | 246 | W |
| Thermal Resistance Junction-Case ¹ | R _{θJC} | 0.51 | °C/W |
| Storage Temperature Range | T _{STG} | -55 to 150 | °C |
| Operating Junction Temperature Range | T _J | -55 to 150 | °C |

Electrical characteristics

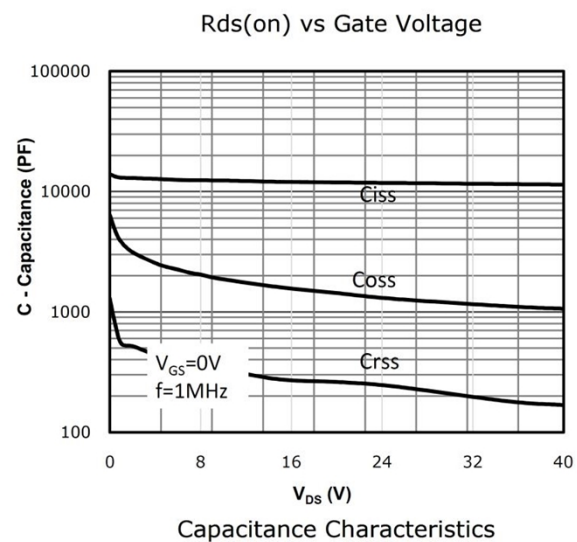
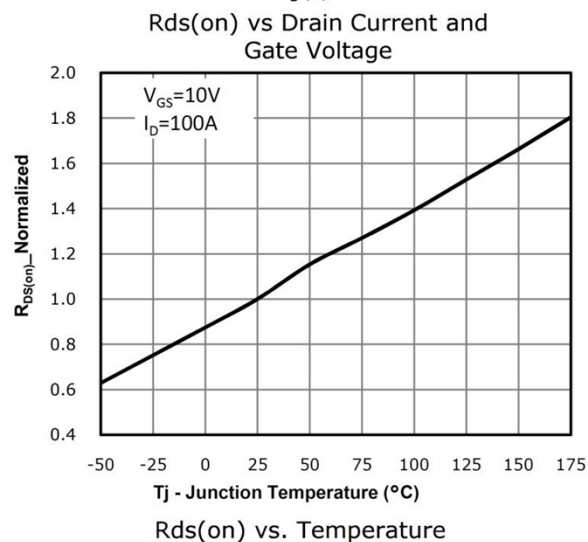
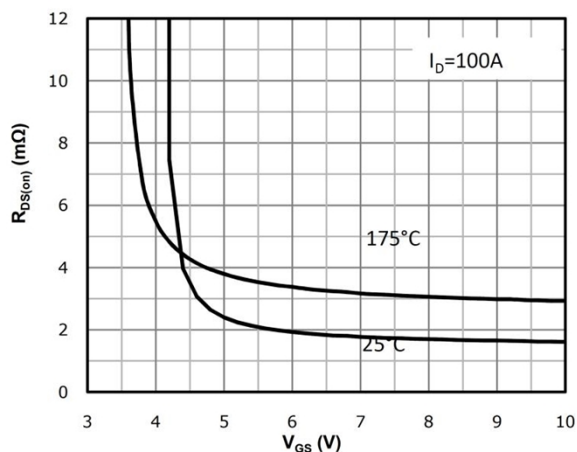
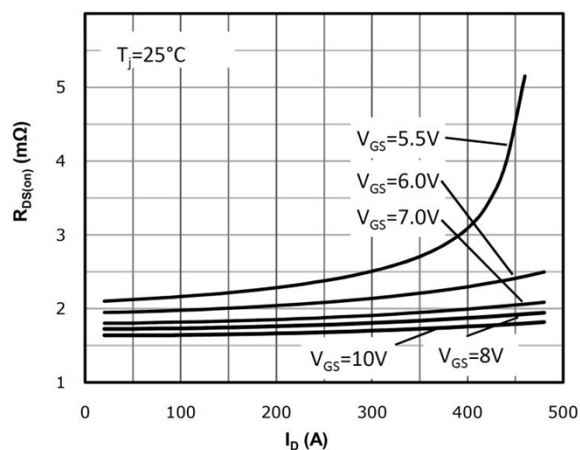
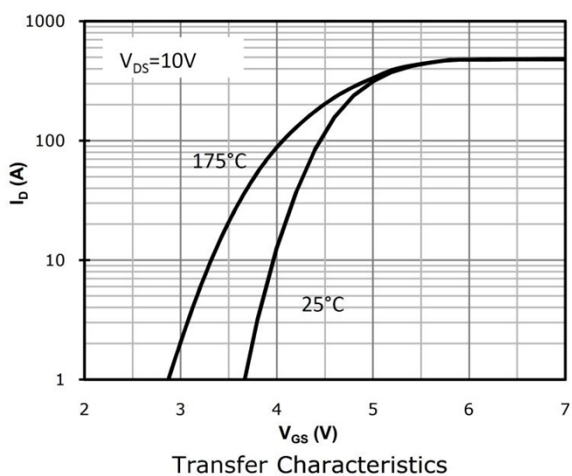
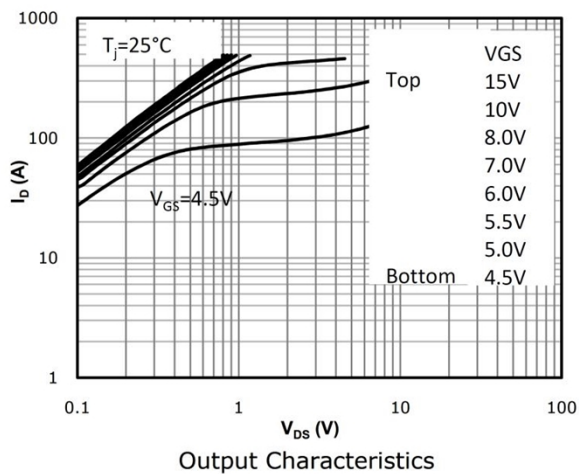
($T_A=25^{\circ}\text{C}$, unless otherwise noted)

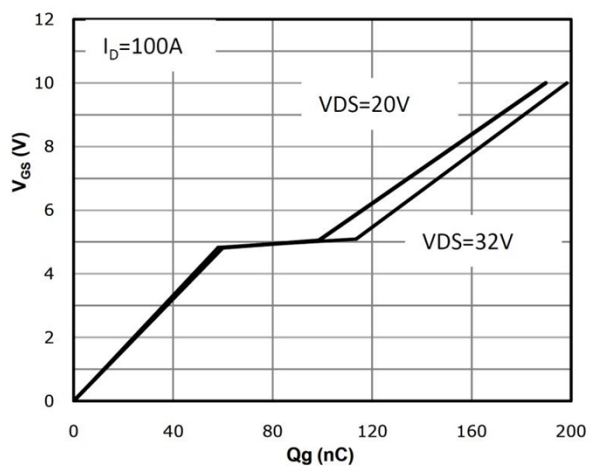
| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|--|---------------------|--|------|-------|------|------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | BV (BR)DSS | V _{GS} = 0V, I _D =250μA | 40 | | | V |
| Drain-Source Leakage Current | I _{DSS} | V _{DS} =32V,V _{GS} = 0V | | | 1 | uA |
| Gate-body leakage current | I _{GSS} | V _{GS} =±20V , V _{DS} =0V | | | ±100 | uA |
| Gate-source threshold voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | 1 | 1.6 | 2.5 | V |
| Static Drain-Source On-Resistance ² | R _{DS(on)} | V _{GS} =10V, I _D =100A | | 1.8 | 2.3 | mΩ |
| | | V _{GS} =4.5V, I _D =30A | | 2.8 | 3.8 | |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =20V, V _{GS} =0V, f=1MHz | | 11485 | | pF |
| Output Capacitance | C _{Oss} | | | 1228 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 259 | | |
| Switching Characteristics | | | | | | |
| Total Gate Charge | Q _g | V _{DS} =20V, V _{GS} =10V, I _D =100A | | 157 | | pF |
| Gate-Source Charge | Q _{gs} | | | 59 | | |
| Gate-Drain Charge | Q _{gd} | | | 31 | | |
| Turn-On Delay Time | T _{d(on)} | V _{DD} =32V, V _{GS} =10V, R _G =2.6Ω, I _D =30A | | 16 | | nS |
| Rise Time | T _r | | | 90 | | |
| Turn-Off Delay Time | T _{d(off)} | | | 192 | | |
| Fall Time | T _f | | | 83 | | |
| Diode Characteristics | | | | | | |
| Diode Forward Voltage ² | V _{SD} | V _{GS} =0V, I _S =1A | | | 1.2 | V |

Note:

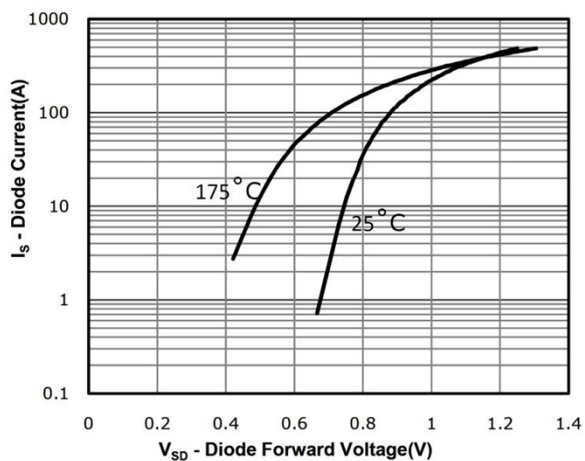
1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
2. The data tested by pulsed , pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
3. The EAS data shows Max. rating . The test condition is $V_{DD} = 20V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$
4. The power dissipation is limited by 150°C junction temperature

Typical Characteristics

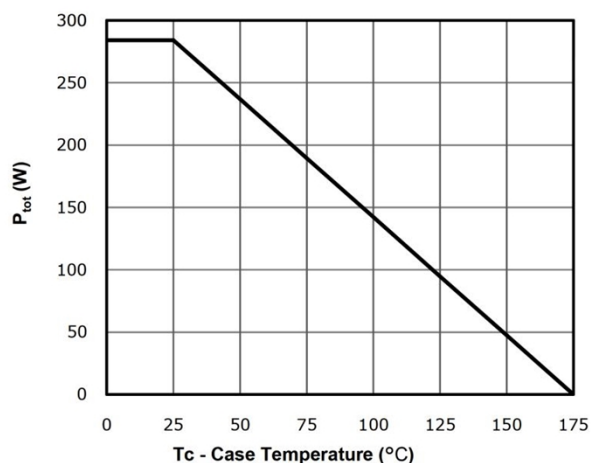




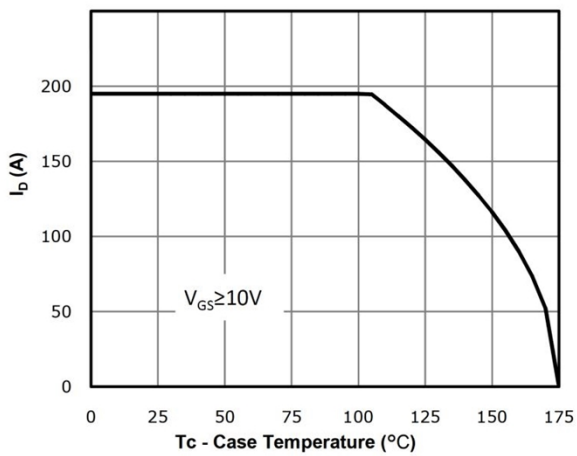
Gate Charge Characteristics



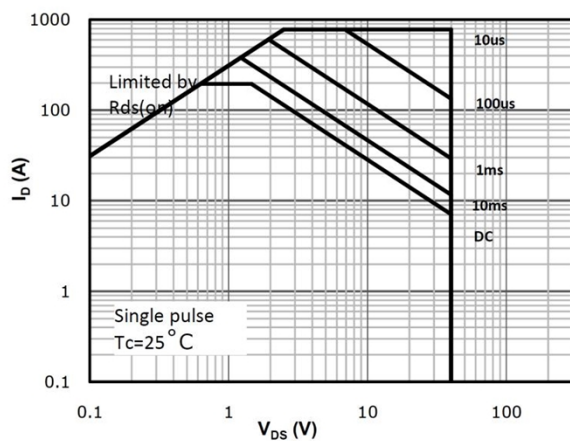
Body-diode Forward Characteristics



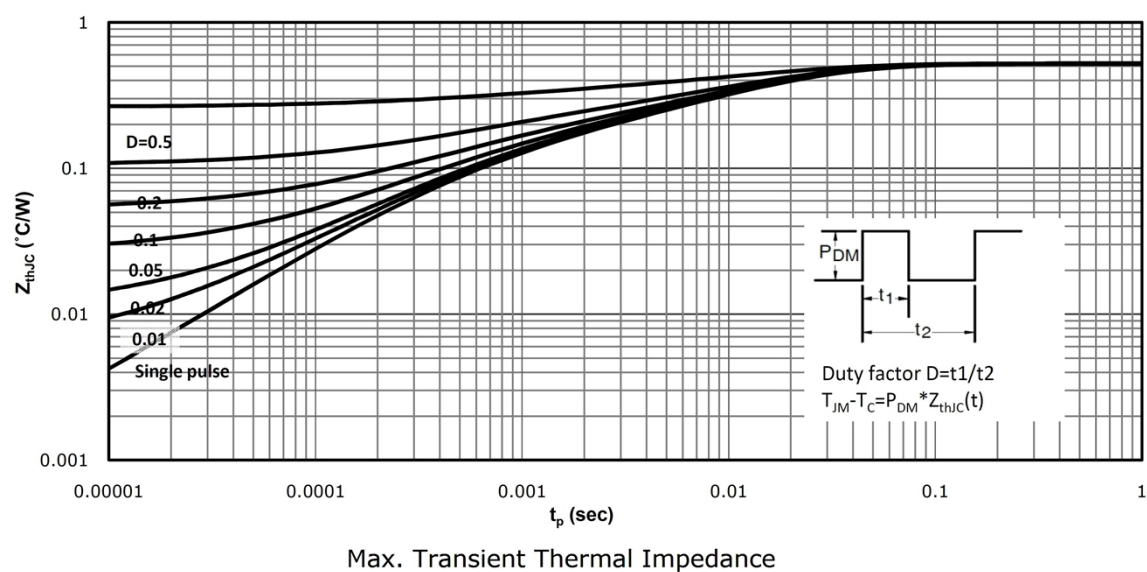
Power Dissipation



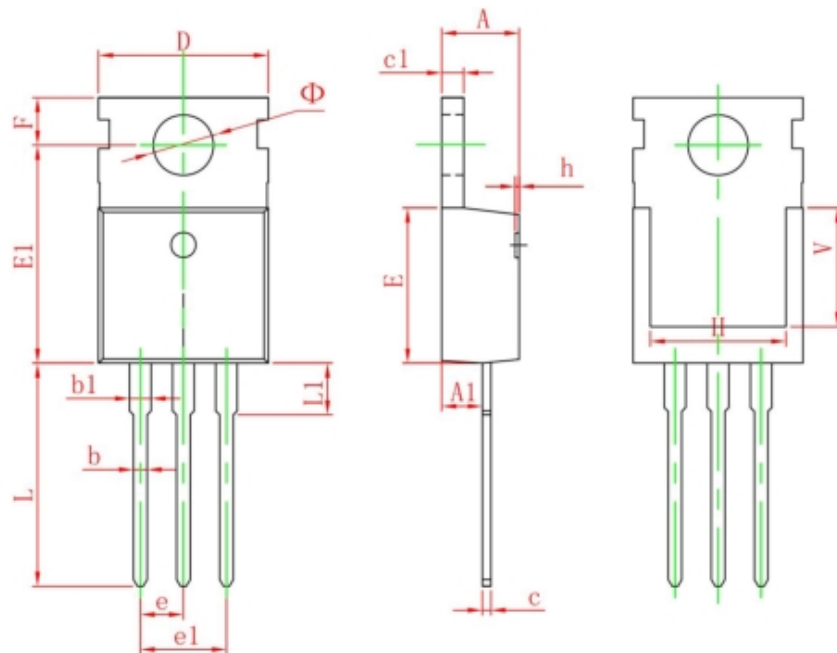
Drain Current Derating



Safe Operating Area



TO-220-3L-C Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|--------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.400 | 4.600 | 0.173 | 0.181 |
| A1 | 2.250 | 2.550 | 0.089 | 0.100 |
| b | 0.710 | 0.910 | 0.028 | 0.036 |
| b1 | 1.170 | 1.370 | 0.046 | 0.054 |
| c | 0.330 | 0.650 | 0.013 | 0.026 |
| c1 | 1.200 | 1.400 | 0.047 | 0.055 |
| D | 9.910 | 10.250 | 0.390 | 0.404 |
| E | 8.950 | 9.750 | 0.352 | 0.384 |
| E1 | 12.650 | 13.050 | 0.498 | 0.514 |
| e | 2.540 TYP. | | 0.100 TYP. | |
| e1 | 4.980 | 5.180 | 0.196 | 0.204 |
| F | 2.650 | 2.950 | 0.104 | 0.116 |
| H | 7.900 | 8.100 | 0.311 | 0.319 |
| h | 0.000 | 0.300 | 0.000 | 0.012 |
| L | 12.900 | 13.400 | 0.508 | 0.528 |
| L1 | 2.850 | 3.250 | 0.112 | 0.128 |
| V | 6.900 REF. | | 0.276 REF. | |
| Φ | 3.400 | 3.800 | 0.134 | 0.150 |